"The Metal-Insulator Transition (MIT) in Two Dimensions: Yet Another Surprise.*"

M.P. Sarachik, City College of New York, CUNY

According to theory and confirmed by experiment, no metallic phase was thought to be possible in two dimensions. It was therefore a big surprise when an apparent metal-insulator transition was reported in 1994 in the strongly interacting 2D electron system in high mobility silicon MOSFETs (Metal Oxide Semiconductor Field Effect Transistors) [1]. A great deal of theoretical and experimental activity ensued to determine whether this is a transition rather than crossover behavior, and to determine the nature of the transition. Most (but not all) experiments (including our own) have claimed to show that this is a quantum phase transition that occurs at a finite electron density $n_c$ in the limit $T \rightarrow 0$. In this talk, I will present new data that holds yet another surprise [2].